Features

19-1906: Rev 0: 2/01

45 Ω , SPDT Analog Switch in SOT23-8

General Description

The MAX4649 is a dual-supply, single-pole/doublethrow (SPDT) analog switch. On-resistance is 45Ω max and flat (7 Ω max) over the specified signal range. The MAX4649 can handle Rail-to-Rail® analog signals, and conducts analog or digital signals equally well in either direction. This switch operates from a single +9V to +36V supply, or from ±4.5V to ±20V dual supplies. The primary application areas are in the switching and routing of signals in telecommunications and test equipment.

The MAX4649 features a switch transition time of 130ns max at +25°C, and a guaranteed break-before-make switching time of 5ns. Off-leakage current is only 2nA max at +25°C.

The MAX4649 is available in a tiny 8-pin SOT23 package.

♦ 5Ω max Ron Match Between Channels

- **Low On-Resistance 45**Ω max ±15V Supplies
- ♦ Guaranteed R_{ON} Flatness Over Specified Signal Range (7 Ω max)
- ♦ V_L Logic Supply Not Required
- ♦ Rail-to-Rail Signal Handling
- ♦ +9V to +36V Single Supply Operation
- ♦ ±4.5V to ±20V Dual Supply Operation
- ♦ Low Crosstalk: -92dB at 1MHz
- ♦ High Off-Isolation: -92dB at 1MHz
- ◆ TTL/CMOS-Compatible Control Inputs

Applications

PBX, PABX Systems Communication Systems

DSL

Test Equipment

Avionics

Audio Systems

Redundant Systems

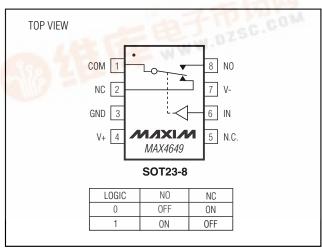
Relay Replacement

PC Multimedia Boards

Ordering Information

PART	TEMP.	PIN-	TOP
	RANGE	PACKAGE	MARK
MAX4649EKA-T	-40°C to +85°C	8-SOT23	AAIE

Pin Configuration



Ra<mark>il-to-Rail is a regis</mark>tered trademark of Nippon Motorola, Inc.

Maxim Integrated Products 1

ABSOLUTE MAXIMUM RATINGS

0.3V to +44.0V
44.0V to +0.3V
0.3V to +44.0V
(V0.3V) to $(V++0.3V)$
±10mA
±30mA
±60mA

Continuous Power Dissipation (TA	
8-Pin SOT23 (derate 8.9mW/°C	above +70°C)714mW
Operating Temperature Range	
MAX4649EKA	40°C to +85°C
Storage Temperature Range	65°C to +150°C
Junction Temperature	+150°C
Lead Temperature (soldering, 10s)+300°C

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual ±15V Supplies

 $(V+ = +15V, V- = -15V, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A = +25$ °C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{NO} , V _{NC} , V _{COM}			V-		V+	V
On-Resistance	Ron	I _{COM} = 1mA; V _{NO} or	+25°C		33	45	Ω
Ori-nesistarice	UON	$V_{NC} = \pm 10V$	T _{MIN} to T _{MAX}			60	52
On-Resistance Matching Between	ΔRon	$I_{COM} = 1mA; V_{NO} or$	+25°C		0.6	5	Ω
Channels	ΔHON	$V_{NC} = \pm 10V$	T _{MIN} to T _{MAX}			6	52
On-Resistance Flatness	R _{FLAT}	I _{COM} = 1mA; V _{NO} or	+25°C		1.5	7	Ω
(Note 4)	(ON)	$V_{NC} = +5V, 0, -5V$	T _{MIN} to T _{MAX}			10	52
NO or NC Off-Leakage	I _{NO(OFF)}	$V_{COM} = -14V, +14V;$ $V_{NO} \text{ or } V_{NC} = +14V,$	+25°C	-2	0.01	2	nA
Current	INC(OFF)	-14V	T _{MIN} to T _{MAX}	-10		10	117 (
COM On-Leakage		$V_{COM} = +14V, -14V;$		-4		4	A
Current	ICOM(ON)	V_{NO} or $V_{NC} = +14V$, -14V or floating	T _{MIN} to T _{MAX}	-20		20	nA
DIGITAL I/O				1			
Input Logic High Voltage	VIH			2.4			V
Input Logic Low Voltage	V _{IL}					0.8	V
Input Leakage	I _{IN}	$V_{IN} = 0 \text{ or } +5V$		-1		1	μΑ

ELECTRICAL CHARACTERISTICS—Dual ±15V Supplies (continued)

 $(V+=+15V, V-=-15V, V_{IH}=2.4V, V_{IL}=0.8V, T_A=T_{MIN}$ to T_{MAX} , unless otherwise noted. Typical values are at $T_A=+25^{\circ}C$.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
DYNAMIC CHARACTERISTICS	1			•			•
Transition Time	trans	V_{NO} or $V_{NC} = \pm 10V$; $R_L = 1k\Omega$;	+25°C		90	130	ns
Transition Time	THANS	$C_L = 35pF$; Figure 2	T _{MIN} to T _{MAX}			170	110
Break-Before-Make Delay	t _D	V_{NO} or $V_{NC} = \pm 10V$; $R_1 = 300\Omega$;	+25°C	5	10		ns
bleak-belole-iwake belay	ıD	$C_L = 35pF$; Figure 3	T _{MIN} to T _{MAX}	2			
Charge Injection	Q	V _{GEN} = 0; R _{GEN} = 0; C _L = 1nF; Figure 4			2		рС
Off-Isolation	Viso	$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$, $V_{COM} = 1V_{RMS}$; Figure 5			92		dB
Crosstalk		$f = 1MHz$, $R_L = 50\Omega$, $C_L = 5pF$; Figure 6			92		
Total Harmonic Distortion	THD	f = 20Hz to $20kHz$, $R_L = 600\Omega$, $5V_{RMS}$			0.015		%
V _{NO} or V _{NC} Off-Capacitance	C _{NO(OFF)} , C _{NC(OFF)}	f = 1MHz; Figure 7			6		pF
COM On-Capacitance	C _{COM} (ON)	f = 1MHz; Figure 8			17		pF
POWER SUPPLY							,
Power-Supply Range				±4.5		±20	V
		V _{IN} = 5V	+25°C		38	75	
Positive Supply Current	l+	V 1 - 0 V	T _{MIN} to T _{MAX}			100	
r oditive dappiy darrent	''	V _{IN} = 0 or V+	+25°C		0.01	1	dB % pF pF
		VIIV — O OI V T	T _{MIN} to T _{MAX}			10	
Negative Supply Current	-	V _{IN} = 0 or 5V	+25°C		0.01	1	μΑ
Triogative Juppiy Jurient	1-	v II/ — O OI O v	T _{MIN} to T _{MAX}			10	μ/ (

ELECTRICAL CHARACTERISTICS—Single +12V Supply

(V+ = +12V, V- = 0, V_{IH} = 2.4V, V_{IL} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{NO} , V _{NC} , V _{COM}			0		V+	V
On-Resistance	D	I _{COM} = 1mA; V _{NO}	+25°C		68	90	Ω
On-nesistance	Ron	or $V_{NC} = +10V$	T _{MIN} to T _{MAX}			115	
On-Resistance Matching Between	ΔRON	I _{COM} = 1mA; V _{NO}	+25°C		0.7	6	Ω
Channels	ZI ION	or $V_{NC} = +10V$	T _{MIN} to T _{MAX}			7	52
On-Resistance Flatness	D	$I_{COM} = 1mA; V_{NO}$	+25°C		9	17	Ω
(Note 4)	RFLAT (ON)	or $V_{NC} = +2V, +6V, +10V$	T _{MIN} to T _{MAX}			23	
DYNAMIC							
Transition Time	ttp.anio.	$V_{NO} \text{ or } V_{NC} = 0,$ 10V or 10V, 0; $R_{L} = 1k\Omega;$	+25°C		116	165	
Transition fille	ttrans	$C_L = 35pF;$ Figure 2	T _{MIN} to T _{MAX}			200	ns 200
Break-Before-Make Delay	tD	V_{NO} or V_{NC} = +10V; R_L = 300 Ω ;	+25°C	1	36		no
Dieak-Deloie-Make Delay	ιD	C _L = 35pF; Figure 3	T _{MIN} to T _{MAX}	1		ns	113
Charge Injection	Ю	$V_{GEN} = 0$; $R_{GEN} = 0$; $C_L = 1$ nF; Figure 4	+25°C		1		рС
POWER SUPPLY							
Power Supply Range				9		36	V
		V _{IN} = +5V	+25°C		22	40	
Positive Supply Current	l+	v IV = +0v	T _{MIN} to T _{MAX}			50	
i ositive supply cufferit	'+	V _{IN} = 0 or V+	+25°C		0.01	1	μА
		VIIV — O OI V+	$T_{\mbox{\scriptsize MIN}}$ to $T_{\mbox{\scriptsize MAX}}$			10	

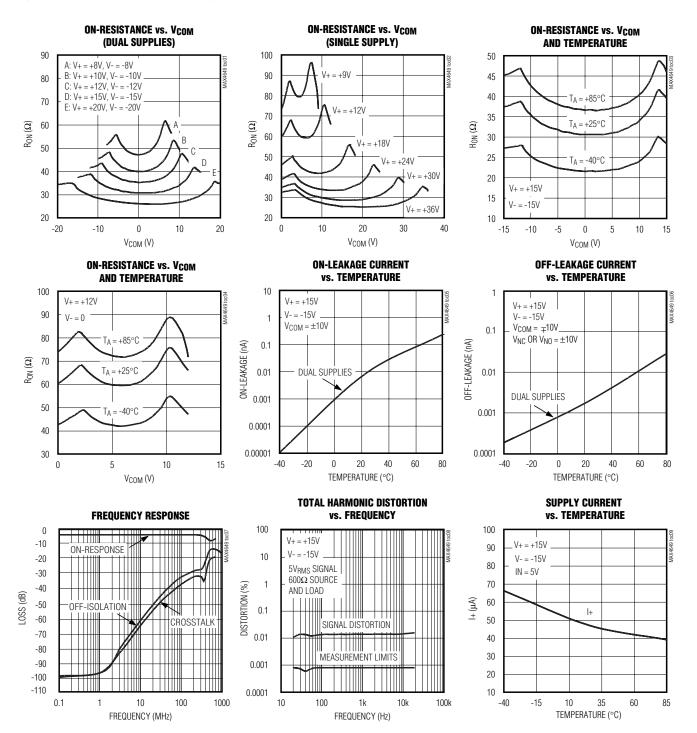
Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 3: All parts are 100% tested at +25°C. Limits across the full temperature range are guaranteed by design and correlation.

Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal range.

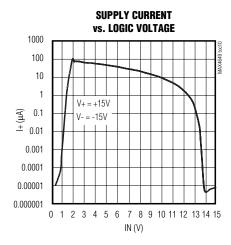
Typical Operating Characteristics

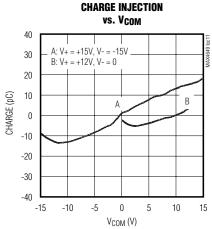
 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

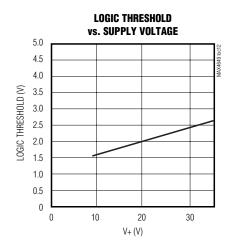


Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$







Pin Description

PIN	NAME	FUNCTION
1	COM	Analog Switch Common
2	NC	Normally Closed Switch Terminal. NC is connected to COM when IN is low.
3	GND	Ground
4	V+	Positive Supply Voltage Input
5	N.C.	No Connection
6	IN	Digital Control Input
7	V-	Negative Supply Voltage Input
8	NO	Normally Open Switch Terminal. NO is connected to COM when IN is high.

Detailed Description

The MAX4649 is a high-voltage, single-pole/double-throw (SPDT) analog switch that operates from dual ±4.5V to ±20V supplies or from a single +9V to +36V supply. The MAX4649 has one normally closed (NC) switch and one normally open (NO) switch. CMOS switch construction allows bidirectional processing of rail-to-rail analog signals.

The MAX4649 has break-before-make switching. The transition time for switching from one input to the other is typically 90ns. The off-leakage is typically less than 10pA, and on-leakage is typically less than 20pA.

Applications Information

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs, NO_, or COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with supply pins (Figure 1). Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the device's low switch resistance and low

leakage characteristics. Device operation is unchanged, and the difference between V+ and V- should not exceed 44V. These protection diodes are not recommended when using a single supply.

Off-Isolation at High Frequencies

In 50Ω systems, the high-frequency on-response of these parts extends from DC to above 300MHz, with a typical loss of -3.6dB. When the switch is turned off,

however, it behaves like a capacitor, and off-isolation decreases with increasing frequency. This effect is more pronounced with higher source and load impedances. Above 5MHz, circuit board layout becomes critical. The graphs shown in the $Typical\ Operating\ Characteristics$ were taken using a 50Ω source and load connected with BNC connectors.

Test Circuits/Timing Diagrams

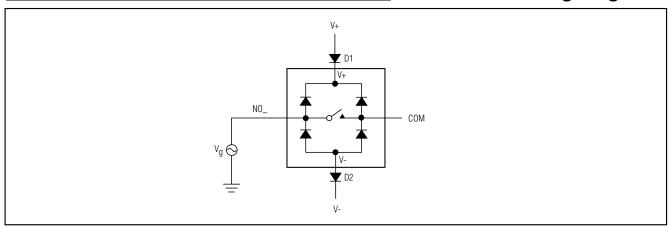


Figure 1. Overvoltage Protection

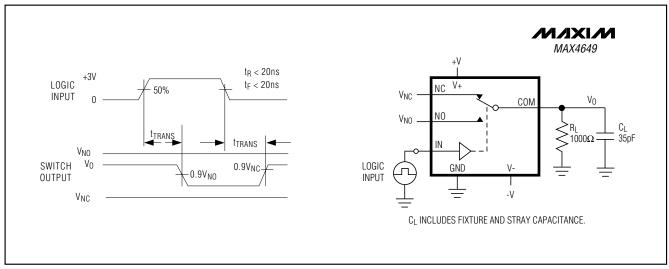


Figure 2. MAX4649 Transition Time

Test Circuits/Timing Diagrams (continued)

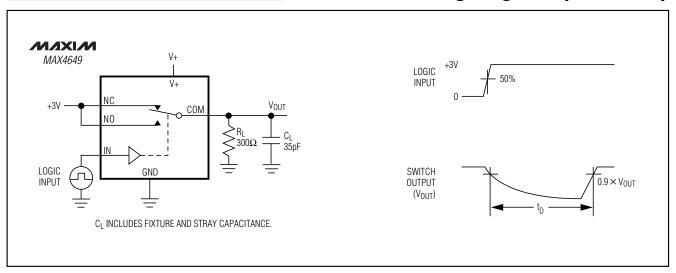


Figure 3. MAX4649 Break-Before-Make Test Circuit

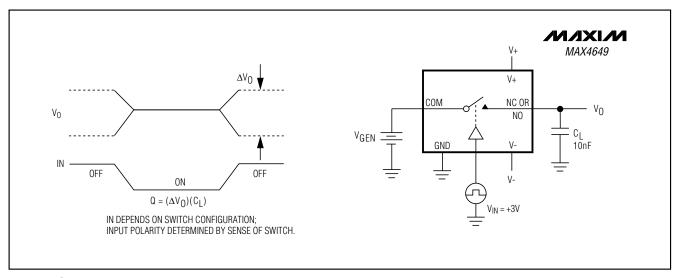


Figure 4. Charge Injection

Test Circuits/Timing Diagrams (continued)

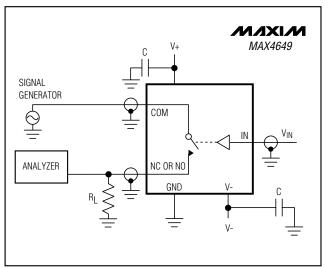


Figure 5. Off-Isolation

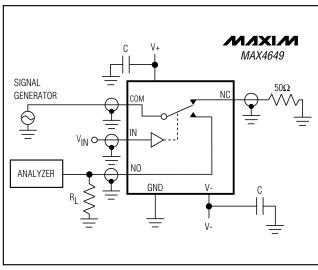


Figure 6. Crosstalk Between Switches

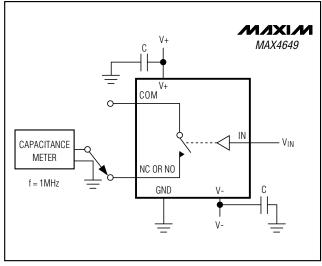


Figure 7. Channel-Off Capacitance

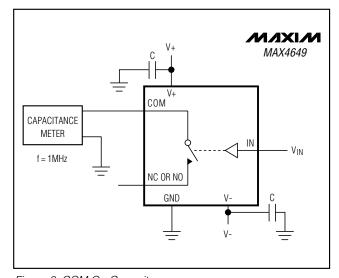
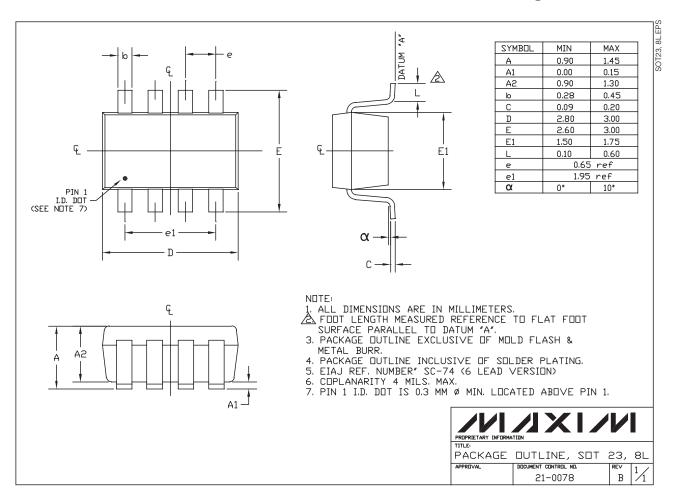


Figure 8. COM On-Capacitance

Chip Information

TRANSISTOR COUNT: 33
PROCESS TECHNOLOGY: CMOS

Package Information



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